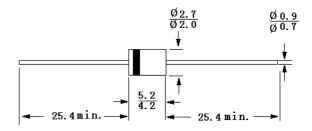
HIGH VOLTAGE SILICON RECTIFIERS Reverse Voltage – 1600 to 1800 Volts Forward Current – 0.1 Amperes

Features

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- · High current capability

DO-41



Dimensions in mm

Mechanical Data

• Case: Molded plastic, DO-41,

• Terminals: Axial leads, solderable per MIL-STD-202. Method 208.

• Polarity: Color band denotes cathode.

Mounting Position: Any.

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz. resistive or inductive

load. For capacitive load, derate current by 20%.

	Symbols	PR1600	PR1800	Units
Maximum recurrent peak reverse voltage	V_{RRM}	1600	1800	V
Maximum RMS voltage	V_{RMS}	1120	1260	V
Maximum DC blocking voltage	V_{DC}	1600	1800	V
Maximum average forward rectified current 9.5 mm lead length @ T_A = 75 $^{\circ}$ C	I _(AV)	0.1		А
Peak forward surge current @ T _A = 125 °C 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	20		А
Maximum instantaneous forward voltage at 0.1A	V _F	15		V
Maximum reverse current $@T_A = 25$ °C	I _R	5 100		μА
Maximum reverse recovery time (Note 1)	t _{rr}	300		nS
Typical junction capacitance (Note 2)	CJ	20		pF
Typical thermal resistance (Note 3)	$R_{\theta JA}$	35		°C/W
Operating junction temperature range	TJ	-65 to +150		°C
Storage temperature range	Ts	-65 to +150		°C

Notes: (1) Measured with $I_F = 0.5A$, $I_R = 1A$, $I_{rr} = 0.25A$.

- (2) Measured at 1MHz and applied reverse voltage of 4VDC.
- (3) Thermal Resistance Junction to Ambient.



SEMTECH ELECTRONICS LTD.

(Subsidiary of Semtech International Holdings Limited, acompany listed on the Hong Kong Stock Exchange, Stock Code: 724)







Dated : 29/10/2004